

AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A polishing composition comprising polymer particles and inorganic particles in an aqueous medium, wherein the inorganic particles have an average particle size of from 5 to ~~170~~ 95 nm, and wherein an average particle size D_p (nm) of said polymer particles and an average particle size D_i (nm) of said inorganic particles satisfy the following formula (1):

$$D_p \leq D_i + 50 \text{ nm} \quad (1)$$

wherein the polymer particles and the inorganic particles have a zeta potential of zero or the same sign.

2. (Original) The polishing composition according to claim 1, wherein the polymer particles are made of a thermoplastic resin.

3. (Original) The polishing composition according to claim 1, wherein the polymer particles are made of a resin having a glass transition temperature of 200°C or less.

4. (Original) The polishing composition according to claim 1, wherein the polymer particles are made of a resin having a degree of cross-linking of 50 or less.

5. (Original) The polishing composition according to claim 1, wherein the inorganic particles are colloidal silica.

6. (Original) The polishing composition according to claim 1, wherein a ratio of C_p/C_i is from 0.03 to 2, wherein C_p is a content of the polymer particles in the polishing composition and C_i is a content of the inorganic particles in the polishing composition.

7. (Original) A polishing process for a substrate to be polished comprising polishing the substrate to be polished with the polishing composition as defined in any one of claims 1 to 6.

8. (Original) A process for improving a rate for polishing a substrate to be polished with the polishing composition as defined in any one of claims 1 to 6.

9. (New) The polishing process according to claim 7, wherein the substrate to be polished is a substrate having silicon dioxide.

10. (New) The polishing process according to claim 7, wherein the substrate to be polished is an aluminum alloy substrate plated with Ni-P.